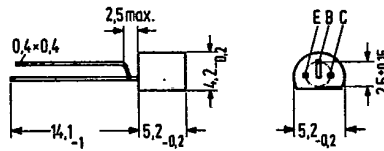


for AF input and driver stages

BC 556, BC 557, BC 558, BC 559, and BC 560 are epitaxial PNP silicon planar transistors in TO 92 plastic package 10 A 3 DIN 41 868. They are intended for use in AF input and driver stages (BC 559, BC 560 for low-noise input stages) and as complementary transistors to BC 546, BC 547, BC 548, BC 549, and BC 550.

Type	Ordering code
BC 556 ¹⁾	Q62702-C692
BC 556 VI	Q62702-C692-V3
BC 556 A	Q62702-C692-V1
BC 556 B	Q62702-C692-V2
BC 557 ¹⁾	Q62702-C693
BC 557 VI	Q62702-C693-V3
BC 557 A	Q62702-C693-V1
BC 557 B	Q62702-C693-V2
BC 558 ¹⁾	Q62702-C694
BC 558 VI	Q62702-C694-V4
BC 558 A	Q62702-C694-V1
BC 558 B	Q62702-C694-V2
BC 558 C	Q62702-C694-V3

Type	Ordering code
BC 559 ¹⁾	Q62702-C695
BC 559 A	Q62702-C695-V1
BC 559 B	Q62702-C695-V2
BC 559 C	Q62702-C695-V3
BC 560 ¹⁾	Q62702-C696
BC 560 A	Q62702-C696-V1
BC 560 B	Q62702-C696-V2
BC 560 C	Q62702-C696-V3



Mounting instruction: Fixing hole dia 0.6
Approx. weight 0.25 g
Dimensions in mm

Maximum ratings		BC 556	BC 557	BC 558	BC 559	BC 560	
Collector-base voltage	$-V_{CBO}$	80	50	30	30	50	V
Collector-emitter voltage	$-V_{CES}$	80	50	30	30	50	V
Collector-emitter voltage	$-V_{CEO}$	65	45	30	30	45	V
Emitter-base voltage	$-V_{EBO}$	5	5	5	5	5	V
Collector current	$-I_C$	100	100	100	100	100	mA
Collector peak current	$-I_{CM}$	200	200	200	200	200	mA
Base peak current	$-I_{BM}$	200	200	200	200	200	mA
Emitter-peak current	$-I_{EM}$	200	200	200	200	200	mA
Junction temperature	T_j	150	150	150	150	150	°C
Storage temperature range	T_{stg}		-65 to +150				°C
Total power dissipation ($T_{amb} = 25^\circ\text{C}$)	P_{tot}	500	500	500	500	500	mW

Thermal resistance

Junction to ambient air	R_{thJA}	≤ 250	≤ 250	≤ 250	≤ 250	≤ 250	K/W
Junction to case	R_{thJC}	≤ 150	≤ 150	≤ 150	≤ 150	≤ 150	K/W

¹⁾ If the order does not include any exact indication of the current amplification group desired, a transistor of a current amplification group just available from stock will be delivered.

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Static characteristics ($T_{amb} = 25^{\circ}\text{C}$)

The transistors are grouped in accordance with the DC current gain h_{FE} and are marked by VI, A, B, and C. At $-V_{CE} = 5\text{ V}$ and the collector currents tabulated below the following static characteristics apply.

Type	BC 556 BC 557 BC 558	BC 556 BC 557, BC 559 BC 558, BC 560	BC 556 BC 557, BC 559 BC 558, BC 560	BC 558, BC 559, BC 560
h_{FE} group	VI	A	B	C
$-I_C$ mA	h_{FE} I_C/I_B	h_{FE} I_C/I_B	h_{FE} I_C/I_B	h_{FE} I_C/I_B
0.01	-	90	150	270
2	110 (75 to 150)	180 (110 to 220)	290 (200 to 450)	500 (420 to 800)
100	-	120 ³⁾	200 ³⁾	400 ³⁾

	BC 556 BC 557 BC 558	BC 559 BC 560	
Collector cutoff current ($-V_{CBO} = 30\text{ V}$)	$-I_{CBO} \leq 15$	≤ 15	nA
($-V_{CBO} = 30\text{ V}; T_{amb} = 150^{\circ}\text{C}$)	$-I_{CBO} \leq 5$	≤ 5	μA
Collector-emitter saturation voltage ($-I_C = 10\text{ mA}; -I_B = 0.5\text{ mA}$)	$-V_{CEsat} 90 (<300)$	$90 (<300)$	mV
($-I_C = 100\text{ mA}; -I_B = 5\text{ mA}$)	$-V_{CEsat} 250 (<650)$	$250 (<650)$	mV
($-I_C = 10\text{ mA}$) ¹⁾	$-V_{CEsat} 300 (<600)$	$300 (<600)$	mV
Base-emitter saturation voltage ²⁾ ($-I_C = 10\text{ mA}; -I_B = 0.5\text{ mA}$)	$-V_{BEsat} 700$	700	mV
($-I_C = 100\text{ mA}; -I_B = 5\text{ mA}$)	$-V_{BEsat} 900$	900	mV
Base-emitter voltage ($-V_{CE} = 5\text{ V}; -I_C = 2\text{ mA}$)	$-V_{BE} 660 (600\text{ to }700)$	$(580\text{ to }700)$	mV
Base-emitter voltage ($-V_{CE} = 5\text{ V}; -I_C = 10\text{ mA}$)	$-V_{BE} <800$	<720	mV

1) For the characteristic which passes through the point $I_C = 11\text{ mA}; V_{CE} = 1\text{ V}$ at constant base current.

2) $\frac{\Delta V_{BEsat}}{\Delta T_1}$ approx. = 1.7 mV/K; $\frac{\Delta V_{BE}}{\Delta T_1}$ approx. = -2 mV/K

3) only applies to BC 556, BC 557, BC 558

Dynamic characteristics ($T_{amb} = 25^{\circ}\text{C}$)

	BC 556 BC 557 BC 558	BC 559	BC 560	
Transition frequency ($-V_{CE} = 5\text{ V}$; $-I_C = 10\text{ mA}$; $f = 100\text{ MHz}$)	f_T 150	300	300	MHz
Collector-base capacitance ($-V_{CBO} = 10\text{ V}$; $f = 1\text{ MHz}$)	C_{CBO} 4.5	2.5 (<4.5)	2.5 (<4.5)	pF
Noise figure ($-V_{CE} = 5\text{ V}$; $-I_C = 200\text{ }\mu\text{A}$; $R_g = 2\text{ k}\Omega$ $f = 1\text{ kHz}$; $\Delta f = 200\text{ Hz}$)	NF 2 (<10)	1 (<4)	1 (<4)	dB
($-V_{CE} = 5\text{ V}$; $-I_C = 200\text{ }\mu\text{A}$; $R_g = 2\text{ k}\Omega$ $f = 30\text{ to }15000\text{ Hz}$)	NF -	1.2 (<4)	1.2 (<2)	dB
Equivalent noise voltage ($-V_{CE} = 5\text{ V}$; $-I_C = 200\text{ }\mu\text{A}$; $R_g = 2\text{ k}\Omega$ $f = 10\text{ to }50\text{ Hz}$)	E_n -	≤ 0.11	≤ 0.11	μV

Dynamic characteristics ($T_{amb} = 25^{\circ}\text{C}$)

$-I_C = 2\text{ mA}$; $-V_{CE} = 5\text{ V}$; $f = 1\text{ kHz}$

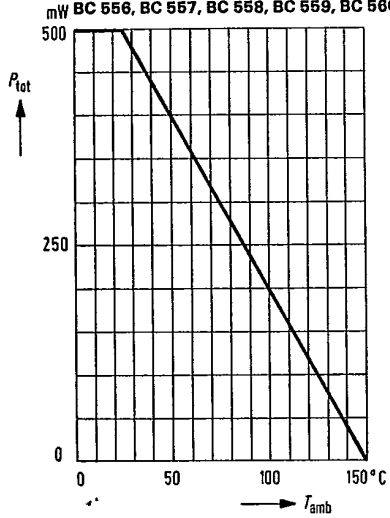
Type	BC 556 BC 557 BC 558	BC 556 BC 557, BC 559 BC 558, BC 560	BC 556 BC 557, BC 559 BC 558, BC 560	BC 558, BC 559, BC 560	
h_{FE} group	VI	A	B	C	
h_{11e}	1.2 (0.4 to 2.2)	2.7 (1.6 to 4.5)	4.5 (3.2 to 8.5)	8.7 (6 to 15)	k Ω
h_{12e}	2.5	1.5	2	3	10^{-4}
h_{21e}	110	220	330	600	-
h_{22e}	20 (<40)	18 (<30)	30 (<60)	60 (<110)	μS

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BC 556 - BC 560

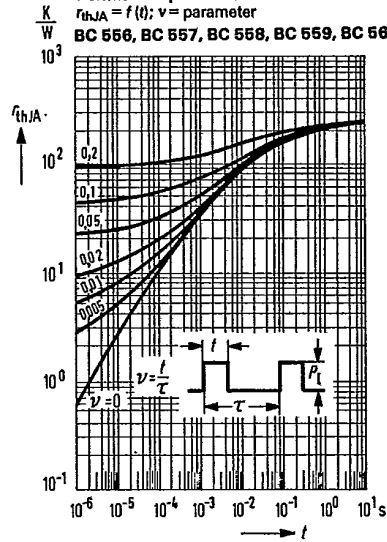
Total perm. power dissipation versus temperature
 $P_{tot} = f(T_{amb})$

BC 556, BC 557, BC 558, BC 559, BC 560



Permissible pulse load
 $r_{thJA} = f(t); v = \text{parameter}$

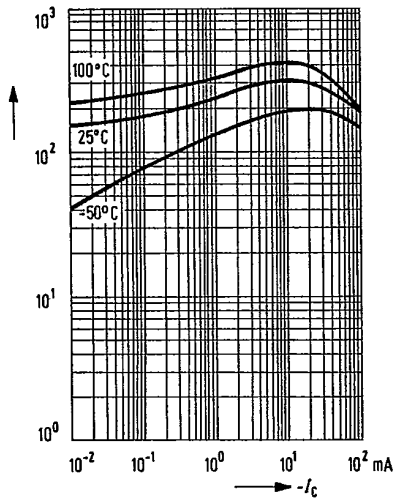
BC 556, BC 557, BC 558, BC 559, BC 560



DC current gain $\beta_{FE} = f(I_C)$

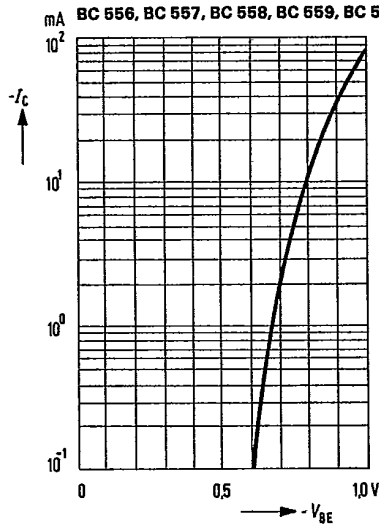
$V_{CE} = 5 \text{ V}; T_{amb} = \text{parameter}$
 (common emitter configuration)

BC 556B, BC 557B, BC 558B, BC 559B, BC 560B



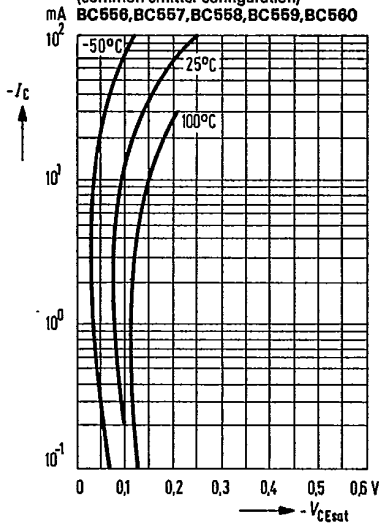
Collector current $I_C = f(V_{BE})$
 $-V_{CE} = 5 \text{ V}$

BC 556, BC 557, BC 558, BC 559, BC 560

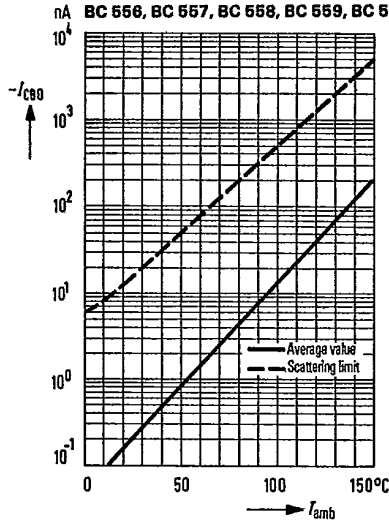


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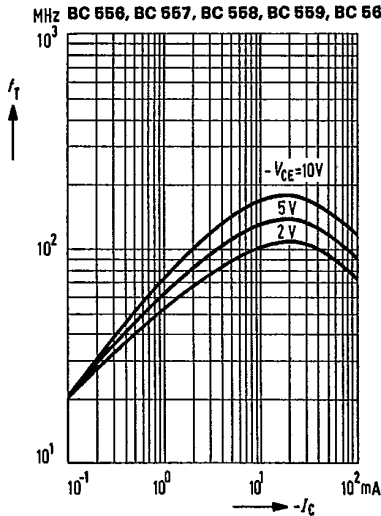
Collector-emitter saturation voltage
 $V_{CEsat} = f(I_C); h_{FE} = 20;$
 $T_{amb} = \text{parameter}$
 (common emitter configuration)
 BC 556, BC 557, BC 558, BC 559, BC 560



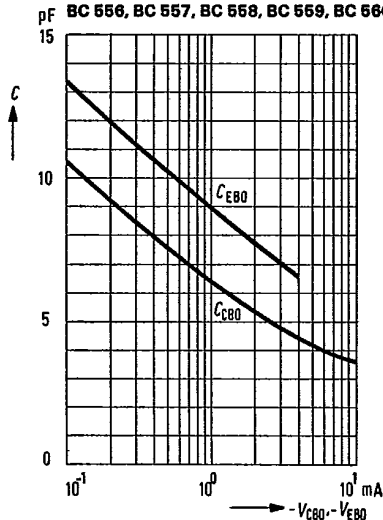
Collector cutoff current versus temperature
 $I_{CBO} = f(T_{amb})$ for max. permissible reverse voltages
 BC 556, BC 557, BC 558, BC 559, BC 560



Transition frequency $f_T = f(I_C)$
 $T_{amb} = 25^\circ\text{C}$
 $V_{CE} = \text{parameter}$
 BC 556, BC 557, BC 558, BC 559, BC 560

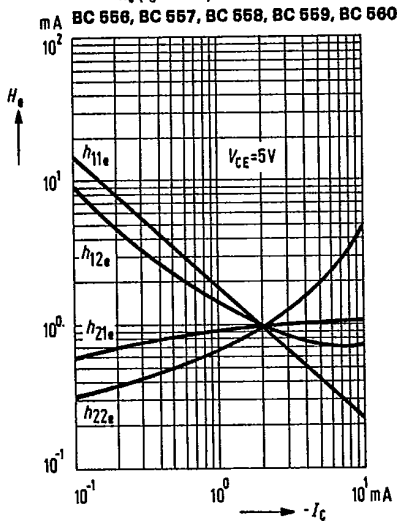


Collector-base capacitance $C_{CB} = f(V_{CBO})$
Emitter-base capacitance $C_{EBO} = f(V_{EBO})$
 $f = 1\text{ MHz}; T_{amb} = 25^\circ\text{C}$
 BC 556, BC 557, BC 558, BC 559, BC 560

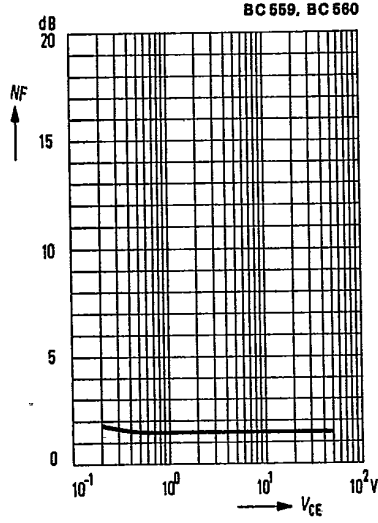


h-parameter versus collector current

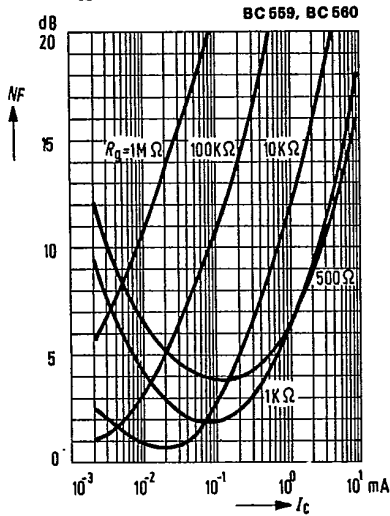
$$H_e = \frac{h_e(I_c)}{h_e(I_c = 2\text{ mA})} = f(I_c)$$



Noise figure $NF = f(V_{CE})$
 $I_c = 0.2\text{ mA}; R_g = 2\text{ k}\Omega; f = 1\text{ kHz}$
 $\Delta f = 200\text{ Hz}; T_{amb} = 25^\circ\text{C}$



Noise figure $NF = f(I_c)$
 $V_{CE} = 5\text{ V}; f = 1\text{ kHz}$



Noise figure $NF = f(I_c)$
 $V_{CE} = 5\text{ V}; f = 120\text{ Hz}$

